

Optically Immersed 2.1 μm Photodiode

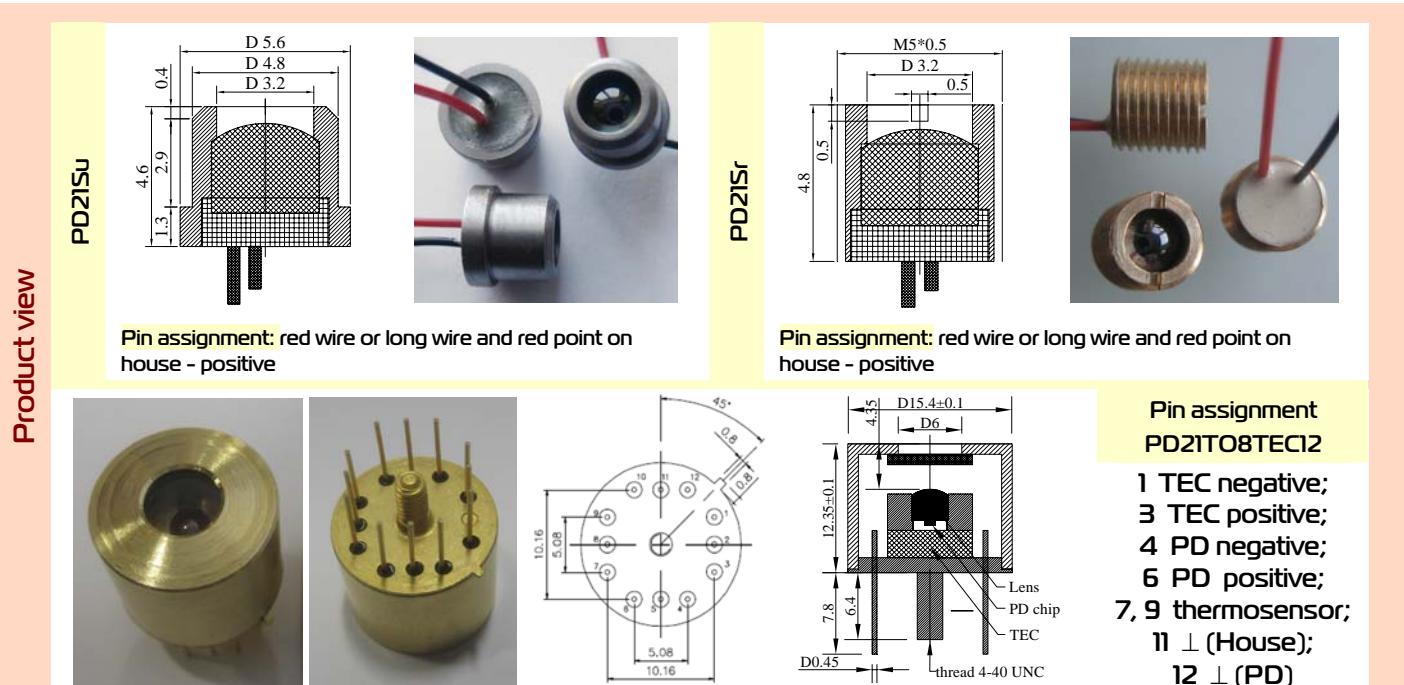
PD21Su, PD21Sr

TE cooled Optically Immersed 2.1 μm Photodiode

PD21TO8TEC

Peak wavelength	λ_{\max}	μm	2.0–2.1	@22 °C
Current sensitivity at λ_{\max}	$S_i(\lambda_{\max})$	A/W	≥0.6	
Shunt Resistance	R_s	kOhm	≥20	
Detectivity	$D^*_{\lambda_{\max}}$	$\text{cmHz}^{1/2}\text{W}^{-1}$	≥ 1.6×10^{11}	
Voltage sensitivity	S_u	V/W	≥12 000	
Switching time	τ	ns	≤20	

Code	Sensitive area, mm	Weight, g	Optical components	Field of view, deg.	Optical axis deviation, deg.	Detectivity deviation in lot, %	Operation conditions, °C	Lifetime, hrs
PD21Su							-60÷+85 ²	
PD21Sr	$\varnothing 3.2$	~0.4	Si lens					
PD21TO8TEC		~10	Si lens and output sapphire window D=6mm	~15	≤5	±25	-60÷+85 ³	>80 000



Product view

Features

- Original growth of narrow gap A3B5 semiconductor alloys onto n⁻-GaSb substrate;
- Flip-chip design of PDs;
- Optical coupling through the use of chalcogenide glasses and Si lenses with antireflection coating
- Ambient and high temperature operation;
- No bias required;
- Operation from DC to VHF;
- Highest long term stability;
- High value of shunt resistance;

Photodiode could be equipped with preamplifier that is designed for conversion of PD photocurrent into a convenient output voltage and is adjusted for the particular PD taking into account the R_o value and frequency range. Other packages are available upon request. Angle of view is small and thus we recommend adjusting PD position regarding to the emission system before final evaluation/use of the devices. Data are valid for PD thermostabilized at 22°C. Heatsink is essential for TEC operation!

Notes	¹ – according to estimation ² – devices have passed through 15 thermo cycles : (20°C, 8 hrs) – transition period of 30 min – (+125°C, 8 hrs) without changes in specifications. Valid for devices produced since 01.2013 ³ – devices have passed through 15 thermo cycles : (-60°C, 30 min) – transition period of 30 min – (+85°C, 30 min) without changes in specifications. Valid for devices produced since 01.2013
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Product specifications are subject to change without prior notice due to improvements or other reasons. Updated 08.05.13

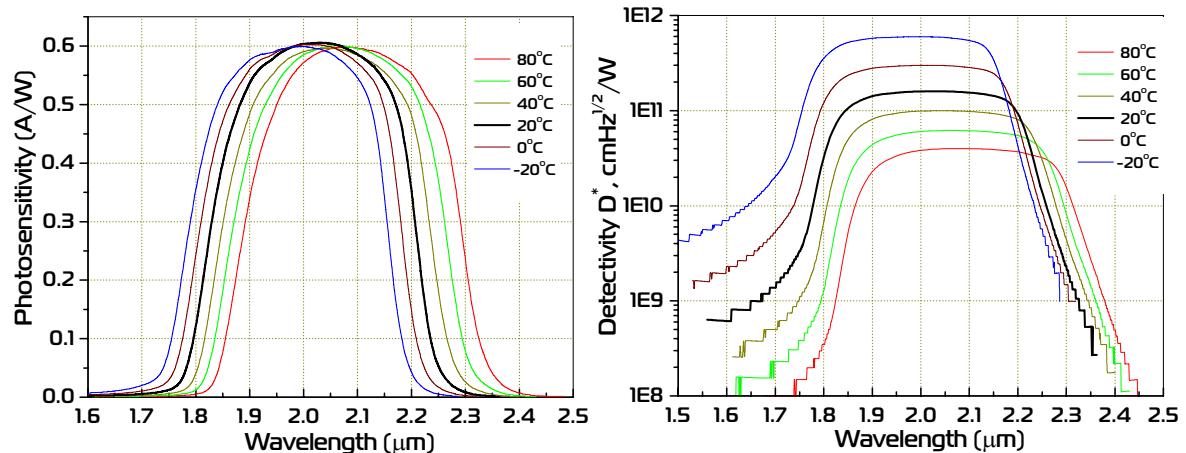


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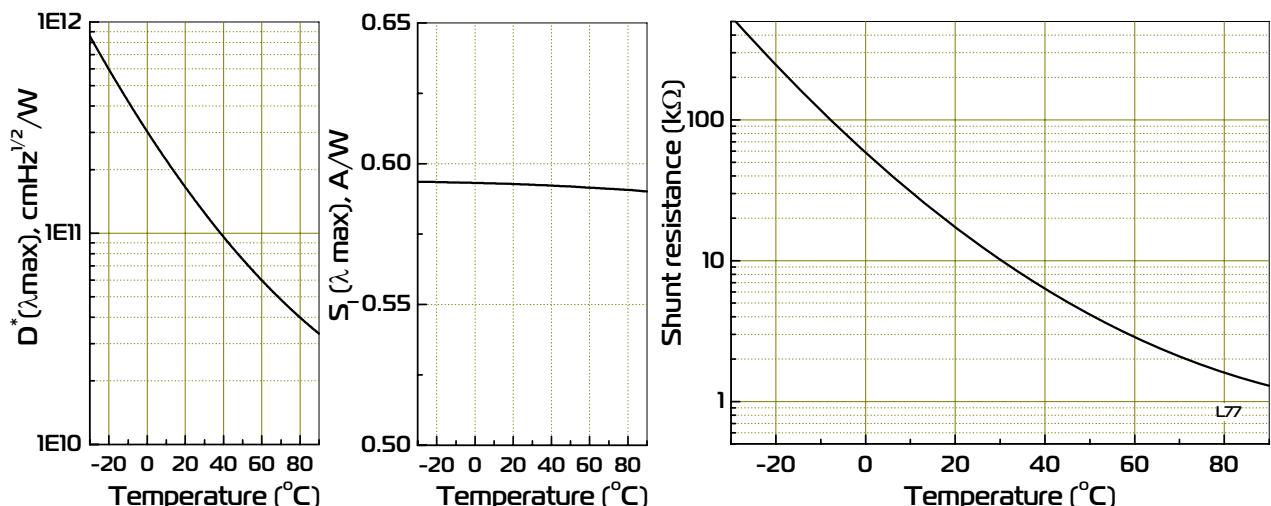
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Spectral response



Detectivity, current sensitivity at λ_{\max} and shunt resistance vs. temperature

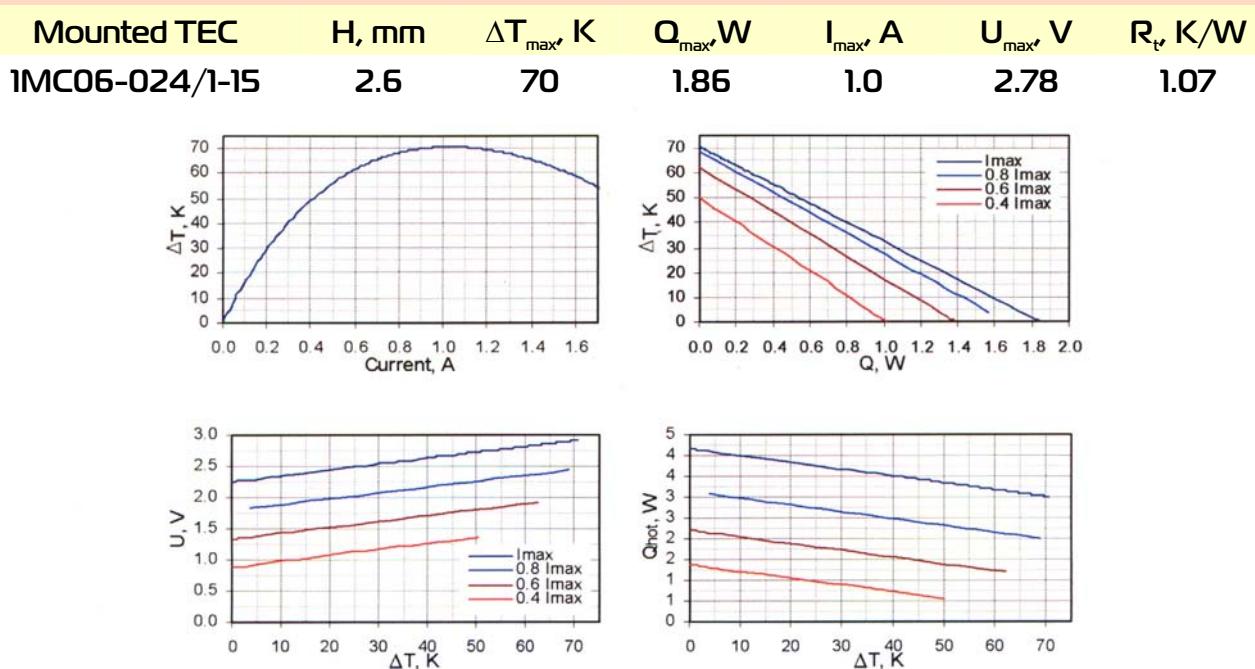


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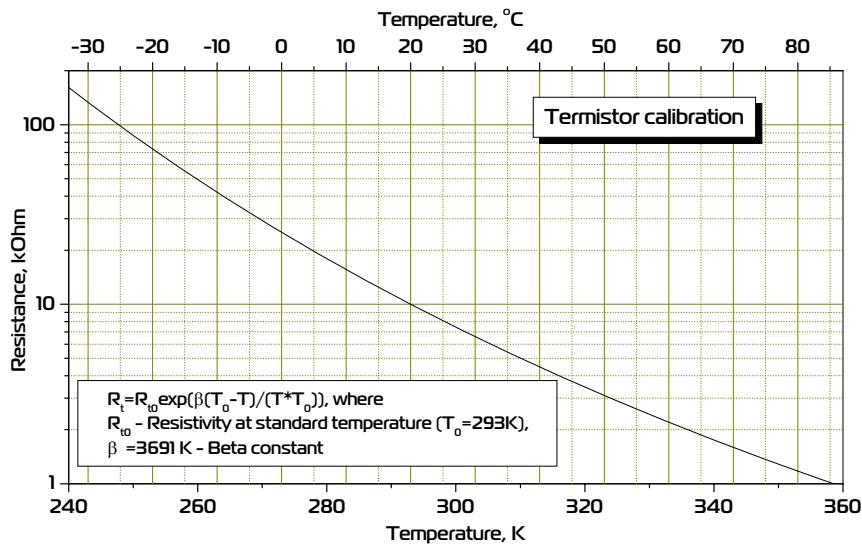
Thermoelectric cooling module datasheet



Data for $T_{hot} = 300$ K, from www.tec-microsystems.com; www.rmtltd.ru

Type TB04-103

T, °C	R, kΩ	T, °C	R, kΩ
-60	1134.5	15	12.44
-55	762.4	20	10.00
-50	521.6	25	8.09
-45	362.8	25	8.09
-40	256.3	30	6.60
-35	183.8	35	5.41
-30	133.6	40	4.47
-25	98.3	45	3.71
-20	73.3	50	3.10
-15	55.2	55	2.61
-10	42.1	60	2.20
-5	32.4	65	1.87
0	25.2	70	1.59
5	19.7	75	1.37
10	15.6	80	1.18



Thermistor specification

Possible TEC heatsink view



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